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PROGRAM

Date: Tuesday, July 5

Opening Session (12:30~12:45)

Chairpersons: M. Kimura, *Ryukoku Univ., JAPAN*

Keynote Address (12:45~15:00)

Chairpersons: N. Matsuki, *Kanagawa Univ., JAPAN*
H. Kajii, *Osaka Univ., JAPAN*
Y. Uraoka, *NAIST, JAPAN*

12:45-13:30 K_1 Organic and Inorganic Materials R&D for High Voltage Perovskite Photovoltaic Devices (INVITED)...1

T. Miyasaka^{1,*}
¹⁾ *Toin University of Yokohama, JAPAN*

13:30-14:15 K_2 Molecular Engineering of Organic Photovoltaics (INVITED)...3

H. Imahori^{1,*}
¹⁾ *Kyoto University, JAPAN*

14:15-15:00 K_3 TFT Interfaces for High Sensory Resolution at Ultralow Power (INVITED)...5

A. Nathan^{1,2*}, J. Yu², C. Jiang³ and H. Ma⁴
¹⁾ *University of Cambridge, UK* ²⁾ *Shandong University, CHINA* ³⁾ *Tsinghua University, CHINA*
⁴⁾ *Chinese Academy of Science, CHINA*

— *Break* —

Symposium 1 : Halide Perovskite Solar Cells:

Towards a Higher Horizon of Evolution (15:20~17:20)

Chairpersons: T. Kaneko, *Tokai Univ., JAPAN*
I. Raifuku, *NAIST, JAPAN*

15:20-15:50 S1_1 Highly Stable Carbon-Based Multi-Porous-Layered-Electrode Perovskite Solar Cells (INVITED)...8

S. Ito^{1,*}, Y. Sakai¹, R. Tsuji¹, T. Shioki¹ and K. Ohishi¹
¹⁾ *University of Hyogo, JAPAN*

15:50-16:20 S1_2 Materials to Improve the Performance of Sn-Based Perovskite Solar Cells (INVITED)...10

A. Wakamiya^{1,*}, S. Hu¹, T. Nakamura¹, T. Handa¹, T. Yamada¹, M. Truong¹, R. Murdey¹, Y. Kanemitsu¹
¹⁾ *Kyoto University, JAPAN*

- 16:20-16:50 S1_3 Characteristics of Halide Perovskites via Low-pressure Vapor-assisted Solution Process (LP-VASP) (INVITED)...12**
H. Yeh¹⁾, Y. Chen¹⁾, W. Hung¹⁾, M. Li¹⁾ and P. Chen^{1,*)}
¹⁾ *National Cheng Kung University, TAIWAN*
- 16:50-17:20 S1_4 Photo-Induced Charge Carrier Dynamics of Metal Halide Perovskite (INVITED)...13**
Y. Tachibana^{1,*)}
¹⁾ *RMIT University, AUSTRALIA*

Symposium 2 : Micro-LED Technologies (17:20~19:00)

Chairpersons: M. Tamaki, *KYOCERA Corp., JAPAN*
Y. Fujiwara, *Osaka Univ., JAPAN*

- 17:20-17:50 S2_1 Micro LED sensor eye-tracking for augmented reality glasses with embedded micro display (INVITED)...17**
C. Luo¹⁾, K. Liang¹⁾, C. Chu¹⁾, C. Lin^{1,2)}, C. Chao¹⁾, W. Kuo¹⁾ and Y. Fang^{1,*)}
¹⁾ *Industrial Technology Research Institute (ITRI), TAIWAN* ²⁾ *National Taiwan University, TAIWAN*
- 17:50-18:20 S2_2 Eu-doped GaN red LEDs for micro-LED displays with extremely high resolution (INVITED)...21**
Y. Fujiwara^{1,*)}, S. Ichikawa¹⁾, D. Timmerman¹⁾, and J. Tatebayashi¹⁾
¹⁾ *Osaka University, JAPAN*
- 18:20-18:40 S2_3 Cylindrical Aerial LED Display...23**
R. Hattori^{1,*)}
¹⁾ *Kyushu University, JAPAN*
- 18:40-19:00 S2_4 A Novel Mini-LED Backlit Driving Circuit Using PWM Mechanism with V_{TH} and V_{SS} I-R Rise Compensation...25**
C. Ke^{1,*)}, Y. Lin²⁾ and C. Lin¹⁾
¹⁾ *National Cheng Kung University, TAIWAN*

Date: Wednesday, July 6

Greeting (9:15~9:25)

**Special Symposium 1 : Variety of Automotive Technology
and Automotive for Future** (9:25~11:25)

Chairpersons: H. Okada, *Univ. of Toyama, JAPAN*
H. Kawanisi, *Ryukoku, JAPAN*

09:25-10:05 SS1_1 Liquid crystal beam steering angle expander for LiDAR applications (INVITED)...29

Y. Li^{1,*}, Z. Luo¹ and S. Wu¹

¹ *University of Central Florida, U.S.A.*

10:05-10:45 SS1_2 High Performance Active-Matrix Light-Emitting Displays Enabled by Vertical Light-Emitting Transistor Technology (INVITED)...33

X. Chen¹, H. Katsui², K. Miyachi², W. Youn¹, I.S. Cho¹, C. Samouce¹, D. Cheney¹, R. Jayaraman¹, A. Titov¹, R. Das¹, A. Schachtner¹, J. Alvarez³, S. Vasilyeva¹, A. Rinzler^{1,3}, M. Lemaitre¹ and B. Liu^{1,*}

¹ *Matrix Technologies, USA* ² *JSR Corporation, JAPAN* ³ *University of Florida, USA*

10:45-11:25 SS1_3 Pixels on The Road - Where Are They Headed? (INVITED)...37

D.S. Hermann^{1,*}

¹ *Volvo Cars, SWEDEN*

— Break —

Special Symposium 2 : Market Overview (11:45~12:25)

Chairpersons: H. Kawanishi, *Ryukoku Univ., JAPAN*
H. Okada, *Univ. of Toyama, JAPAN*

11:45-12:25 SS2_1 Automotive display design and technology trends (INVITED)...45

S. Wu^{1,*}

¹ *Omdia, TAIWAN*

— Lunch —

**Special Symposium 3 : High Performance Automotive Displays
and Manufactures** (13:55~15:15)

Chairpersons: M. Furuta, *Kochi Univ. of Technol., JAPAN*
R. Hattori, *Kyushu Univ., JAPAN*

13:55-14:35 SS3_1 High-Performance Interactive Display Technologies for Automotive Applications (INVITED)...48

Y. Ito^{1,*} and H. Ikeno¹

¹ *Tianma Japan, JAPAN*

14:35-15:15 SS3_2 Manufacturing Equipment Technology for Automotive Display (INVITED)...52

T. Kikuchi^{1,*}

¹⁾ULVAC, Inc.

— Break —

Special Symposium 4 : Free-form, Bendable Automotive Display and Unit of Mobility and Innovation Systems (15:35~16:55)

Chairpersons: R. Hattori, *Kyushu Univ., JAPAN*
M. Furuta, *Kochi Univ. of Tech., JAPAN*

15:35-16:15 SS4_1 OLCD in Automotive Applications – Enabling Curved and Non-Rectangular Form Factors with Conformable Displays (INVITED)...56

J. Huggins^{1,*}, M. Wheeler¹⁾, A. Russell¹⁾ and A. James¹⁾ ¹⁾

FlexEnable, UK

16:15-16:55 SS4_2 Creating the Mobility and Technology Experience – Trip specific assessment of automotive display applications (INVITED)...60

Dipl.-Wi.-Ing. Sebastian Stegmüller^{1,*}

¹⁾*Fraunhofer Institute for Industrial Engineering IAO, GERMANY*

Closing (16:55~17:05)

Date: Thursday, July 7

**Session 1 : Emerging Science, Materials, and Engineering
in Solar Cells** (9:15~10:25)

Chairpersons: A. Wakamiya, *Kyoto Univ., JAPAN*
A. Saeki, *Osaka Univ., JAPAN*

09:15-09:40 1_1 Crystal Chemistry of Organo-Lead Halide Perovskite Solar Cells (INVITED)...64

S. Uchida^{1,*} and H. Segawa¹

¹*University of Tokyo, JAPAN*

09:40-10:05 1_2 Advanced Technologies for Ultra-Flexible and Highly Stable Organic Solar Cells (INVITED)...66

K. Fukuda^{1,*} and T. Someya^{1,2}

¹*RIKEN, JAPAN* ²*The University of Tokyo, JAPAN*

10:05-10:25 1_3 Stabilizing Perovskite Crystals by Fixing The Position of Potassium Ion...70

C. Zhang¹ and H. Okada^{1,*}

¹*University of Toyama, JAPAN*

— Break —

**Symposium 3 : Recent Advances in TFT Technologies
for Future Electronics** (10:45~12:15)

Chairpersons: T. Nagase, *Osaka Metropolitan Univ., JAPAN*
S. Horita, *JAIST, JAPAN*

10:45-11:15 S3_1 Recent Progress of Oxide TFT Based Inverter Technology (INVITED)...72

K. Nomura^{1,*}

¹*University of California San Diego, USA*

11:15-11:45 S3_2 Ferroelectric Thin-Film Transistors for Memory and Neuromorphic Device Applications (INVITED)...76

J. Lee^{1,*}

¹*POSTECH, KOREA*

11:45-12:15 S3_3 T-Shaped Poly-Si Thin-Film Transistor Technology for Advanced Logic and RF Applications (INVITED)...78

H. Lin^{1,*}, C. Lee¹, P. Yu¹, P. Li¹, K. Chen² and G. Huang²

¹*National Yang Ming Chiao Tung University, TAIWAN* ²*Taiwan Semiconductor Research Institute (TSRI), TAIWAN*

— Lunch —

**Symposium 4: Development of Emerging
and Neuromorphic Devices** (13:45~15:15)

Chairpersons: H. Kajii, *Osaka Univ., JAPAN*
Shyam S. Pandey, *Kyushu Inst. of Tech., JAPAN*

- 13:45-14:15 S4_1 Development of Neuromorphic Systems and Emerging Devices : Revolutionize Artificial Intelligence with Your Devices !! (INVITED)...82**
 M. Kimura^{1,2,*}
¹⁾ Ryukoku University, JAPAN ²⁾ Nara Institute of Science and Technology, JAPAN
- 14:15-14:45 S4_2 Construction of a neural network using organic materials and ions (INVITED)...86**
 N. Hagiwara²⁾, S. Kan²⁾, T. Asai²⁾ and M. Akai-kasaya^{1,2,*}
¹⁾ Osaka University, JAPAN ²⁾ Hokkaido University, JAPAN
- 14:45-15:15 S4_3 In-Materio Computing Devices Composed of Random Network Nanoparticles for Future Autonomous Robot Operation (INVITED)...90**
 H. Tanaka^{1,*}
¹⁾ Kyushu Institute of Technology, JAPAN

Poster Session (15:30~17:00)

- P_1 Novel AMOLED Compensation Pixel Circuit Design with Low Frame Rate for Portable Displays...92**
 C. Fan^{1,2)}, W. Lin^{1,*} and C. Chen¹⁾
¹⁾ National Taiwan University of Science and Technology, TAIWAN
- P_2 New Compensating Pixel Circuit to Mitigate Impact of Leakage Currents on OLED Currents for AMOLED Displays...95**
 W. Shieh^{1,*}, C. Tsai¹⁾, B. Chen¹⁾ and C. Lin¹⁾
¹⁾ National Cheng Kung University, TAIWAN
- P_3 Dependence of Conversion Properties in GTO Thin Film Thermoelectric Devices on Hydrochloric Acid Concentration in Mist CVD Method...99**
 R. Ito^{1,*}, S. Sugisaki¹⁾, Y. Yamamoto¹⁾, N. Shibata¹⁾ and M. Kimura¹⁾
¹⁾ Ryukoku University, JAPAN
- P_4 Spike-Timing-Dependent-Plasticity Characterization of Ga-Sn-O Thin Film Synaptic Device...102**
 K. Yachida^{1,*}, T. Katagiri¹⁾, N. Komai¹⁾, N. Sahara¹⁾ and M. Kimura^{1,2)}
¹⁾ Ryukoku University, JAPAN ²⁾ Nara Institute of Science and Technology, JAPAN
- P_5 Research on structural stabilization method of GeO₂ film and improvement of electrical characteristics...106**
 H. Iino^{1,*}, T. Shibuya¹⁾, Y. Iwazaki¹⁾ and T. Ueno¹⁾
¹⁾ Tokyo University of Agriculture and Technology, JAPAN
- P_6 Study on Fabrication of GeO₂/Ge Structure with Good Interfacial Properties...110**
 K. Ito¹⁾, K. Matsuura^{1,*}, H. Takahashi¹⁾, H. Saito¹⁾, Y. Iwazaki¹⁾ and T. Ueno¹⁾
¹⁾ Tokyo University of Agriculture and Technology, JAPAN
- P_7 Solid-Phase Crystallization Characteristics of Interface-Modulated Sn-Doped Ge Thin Films on Insulator with Capping...114**
 T. Nagano^{1,*}, R. Hara¹⁾ and T. Sadoh¹⁾
¹⁾ Kyushu University, JAPAN
- P_8 Interplay of Viscosities in Controlling The Orientation of Conjugated Polymer Thin Films Fabricated by Floating Film Transfer Method...116**
 S. Sharma^{1,*}, A.K. Vats²⁾, S. Nagamatsu¹⁾ and S.S. Pandey¹⁾
¹⁾ Kyushu Institute of Technology, JAPAN ²⁾ Nara Advanced Institute of Science and Technology, JAPAN
- P_9 GTO thin film thermoelectric conversion device annealed in vacuum and in air...120**
 Y. Yamamoto^{1,*}, R. Ito¹⁾, N. Shibata¹⁾ and M. Kimura¹⁾
¹⁾ Ryukoku University, JAPAN
- P_10 Fabrication and Characterization of Oriented Thin Films of DPP-Based Conjugated Copolymer Prepared by Friction Transfer Method...124**
 Y. Kurokawa^{1,2,*}, A.K. Vats²⁾, S. Nagamatsu³⁾ and S.S. Pandey¹⁾
¹⁾ Graduate School of Life Science and Systems Engineering, JAPAN ²⁾ Nara Institute of Science and Technology, JAPAN ³⁾ Kyushu Institute of Technology, JAPAN
- P_11 Fabrication of ZnO Nanorods and Applied for Flexible Dye-Sensitized Solar Cells...128**
 H.S. Wai^{1,*}, M. Morimoto¹⁾ and C. Li¹⁾
¹⁾ Kochi University of Technology, JAPAN

P_12 Photoinduced Phase Transition and Subsequent Change in Adhesion Property of Cyanostilbene Liquid Crystalline Polymer Composite...132

M. Kondo^{1,*}, S. So¹, T. Nagata¹, H. Adachi¹, D. Okai¹ and N. Kawatsuki¹

¹ *University of Hyogo, JAPAN*

P_13 Photon Flux Density Dependence of Nanographene Synthesis by Soft X-Ray Irradiation From Pentacene-Based Molecules Prepared on Ni Films by Hot Mesh Deposition...136

A. Heya^{1,*}, K. Kanda¹, R. Yamasaki² and K. Sumitomo¹

¹ *University of Hyogo, JAPAN* ² *Tocalo Co., Ltd., JAPAN*

P_L1 Fixed Charge Induced by Ion Implantation Used to Control The Threshold Voltage for Oxide TFTs...138

T. Sakai^{1,*}, D. Matsuo¹, M. Fujiwara¹, D. Azuma¹, Y. Setoguchi¹, Y. Andoh¹, E. Takahashi¹ and T. Sameshima²

¹ *NISSIN ELECTRIC CO., JAPAN* ² *Tokyo University of Agriculture and Technology, JAPAN*

P_L2 Performance of N- and P-Ch Self-Aligned Planar Double-Gate Cu-MIC Poly-Ge TFTs on Glass Substrates...140

S. Suzuki^{1,*}, K. Tomizuka¹ and A. Hara¹

¹ *Tohoku Gakuin University, JAPAN*

P_L3 Four-Terminal Poly-Si Thin-Film Transistors with High-K Gate Dielectric on Glass Substrate and Its Application in CMOS Inverters...142

K. Nomura^{1,*}, A. Nagayosi¹ and A. Hara¹

¹ *Tohoku Gakuin University, JAPAN*

P_L4 In-Ga-Zn-O TFT Using Hf_{0.5}Zn_{0.5}O₂ Deposited by RF Magnetron Sputtering As The Gate Insulating Film...144

T. Fukui^{1,*}, K. Nakagawa¹, R. Eda¹, H. Kawanishi¹ and M. Kimura¹

¹ *Ryukoku University, JAPAN*

P_L5 Influence of Sn Concentration on The Performance of Solution Combustion Synthesis-Assisted Si_xSn_yO Thin-Film Transistors...146

C.G.P. Quino^{1,*}, J.P. Bermundo¹, M. Uenuma¹ and Y. Uraoka¹

¹ *Nara Institute of Science and Technology, JAPAN*

P_L6 Investigation of Infrared Absorption Properties of InGaZnO Thin Film in TFT Using Monochromated STEM-EELS...148

N. Kawasaki^{1,*}, S. Inamoto¹ and Y. Otsuka¹

¹ *Toray Research Center Inc., JAPAN*

P_L7 Fabrication and Characteristics of Weak Microcavity AC-Driven Insulated Polymer Electroluminescent Devices with Dielectric Film Mirrors Utilizing Ferroelectric Polymer Poly(Vinylidene Fluoride-Trifluoroethylene) Film...150

H. Kajii^{1,*}, Y. Takayama¹, M. Morifuji¹ and M. Kondow¹

¹ *Osaka University, JAPAN*

P_L8 Synaptic Characteristics of Ferroelectric Capacitors for Neuromorphic Systems...152

Y. Ishisaki^{1,*}, O. Tanaka¹, T. Kuwahara¹, H. Kawanishi¹ and M. Kimura¹

¹ *Ryukoku University, JAPAN*

P_L9 ReRAM Multi-Level Characteristics for Analog Computing...154

T. Katagiri^{1,*}, K. Morigaki¹, K. Yachida¹, H. Kawanishi¹ and M. Kimura¹

¹ *Ryukoku University, JAPAN*

Date: Friday, July 8

Session 2 : Recent Progress in Flat Panel Display 1 (9:15~10:20)

Chairpersons: R. Reiji, *Kyushu Univ., JAPAN*
T. Mori, *Aichi Inst. of Tech., JAPAN*

- 09:15-09:40 2_1 FOD Solution with High-PPI Flexible Image Sensor under OLED Panel (INVITED)...156**
F. Lu^{1,*}, H. Yu¹, K. Li¹, W. Guo¹, Q. Yao¹, Y. Zeng¹, Y. Wu¹ and Y. Ding¹
¹ *Shanghai Tianma Microelectronics Co., CHINA*
- 09:40-10:00 2_2 Stretchable AMOLED Display Pixel Circuit Compensating for V_{Th} Variation and Strain Effect...160**
J. Kang^{1,*}, K. Kang¹, J. Park¹, M. Kong¹ and S. Lee¹
¹ *Seoul National University, KOREA*
- 10:00-10:20 2_3 Crosstalk and Uniformity Analysis of Fingerprint-On-Display Technology Using Pinhole Imaging Technique...164**
M.A.B. Misran^{1,*} and R. Hattori¹
¹ *Kyushu University, JAPAN.*

— *Break* —

Session 3 : Intelligent Devices and Systems (10:40~11:45)

Chairpersons: A. Heya, *Univ. of Hyogo, JAPAN*
H. Kajii, *Osaka Univ., JAPAN*

- 10:40-11:05 3_1 Phase Diagram Construction Supported by Artificial Intelligence (INVITED)...168**
R. Tamura^{1,*}
¹ *International Center for Materials Nanoarchitectonics(MANA), National Institute for Materials Science, JAPAN*
- 11:05-11:25 3_2 Character Inference Learning for Stacked Neuromorphic Devices Using IGZO Thin Films...171**
E. Iwagi^{1,*}, M. Kimura^{1,2}
¹ *Ryukoku University, JAPAN* ² *Nara Institute of Science and Technology, JAPAN*
- 11:25-11:45 3_3 Structural Modification of Solution-Processed Barium Titanate/Polysiloxane Nanocomposite for Memory Application...175**
A.S. Safaruddin^{1,*}, J.P.S. Bermundo¹, M. Uenuma¹, A. Yamamoto², M. Kimura³ and Y. Uraoka
¹ *Nara Institute of Science and Technology, JAPAN* ² *Merck Electronics, JAPAN* ³ *Ryukoku University, JAPAN*

— *Lunch* —

Session 4:Recent Progress in Flat Panel Display 2 (13:15~14:15)

Chairpersons: T. Mori, *Aichi Inst. of Tech., JAPAN*
R. Hattori, *Kyushu Univ., JAPAN*

- 13:15-13:35 4_1 Material Networks for Neuromorphic Computing...179**
T. Matsumoto^{1,*}
¹ *Osaka University, JAPAN*

- 13:35-13:55 **4_2 High-Performance Bio-Memristive Devices with Natural Egg Albumen as a Switching Layer...181**
S. Chattaraj¹⁾, A. Dwivedi¹⁾, G. Konwar¹⁾, A. Lodhi¹⁾, S. Saini¹⁾ and S.P. Tiwari^{1,*)}
¹⁾ *Indian Institute of Technology Jodhpur, INDIA*
- 13:55-14:15 **4_3 Fabrication of ZnCuInS/ZnS Based Quantum-Dot Light-Emitting Diodes with Variation of Hole Transport Materials in Mixed Single Layer...185**
M.M.R. Biswas^{1,*)} and H. Okada¹⁾
¹⁾ *University of Toyama, JAPAN*

— Break —

Session 5 : Advanced Process and Materials for TFT and Display Technologies (14:35~15:40)

Chairpersons: H. Kumomi, *Tokyo Inst. of Tech./ JST, JAPAN*
T. Miyakawa, *NHK Sci. & Technol. Res. Labs., JAPAN*

- 14:35-15:00 **5_1 Solid Phase Crystallization of Hydrogenated Indium Oxide (InO_x:H) for High Mobility Thin-Film Transistors (INVITED)...187**
M. Furuta^{1,*)}, T. Kataoka¹⁾, Y. Magari²⁾ and W. Yeh²⁾
¹⁾ *Kochi University of Technology, JAPAN* ²⁾ *Shimane University, JAPAN*
- 15:00-15:20 **5_2 High Performance Flexible Organic Transistors with Biodegradable Natural-Protein Based Gate Dielectrics...190**
G. Konwar,^{1,*)} P. Saxena¹⁾, V. Raghuvanshi¹⁾, S. Rahi¹⁾ and S.P. Tiwari¹⁾
¹⁾ *Indian Institute of Technology Jodhpur, INDIA*
- 15:20-15:40 **5_3 Comparative Study of Cu Film Properties on CuMn and Mo Adhesion Layers Use as Bottom Electrodes in Display Devices...194**
H. Kim^{1,*)}, B. Zhu¹⁾, M. Huang¹⁾, R. Vaddi¹⁾ and R.G. Manley¹⁾
¹⁾ *Corning Research and Development Corporation, USA*

LATE NEWS (15:40~16:10)

Chairpersons: H. Kumomi, *Tokyo Inst. of Tech./ JST, JAPAN*
T. Nagase, *Osaka Metropolitan Univ., JAPAN*

- 15:40-15:55 **L_1 Direct Patterning Process Development for Solution Based Electrodes of TFTs...198**
S. Tanaka^{1,*)}, M. Miyakawa¹⁾, H. Tsuji¹⁾, T. Takei¹⁾ and M. Nakata¹⁾
¹⁾ *NHK Science & Technology Research Laboratories, JAPAN*
- 15:55-16:10 **L_2 Electrical Performance Improvement of All-Solution Processed Indium Zinc Oxide Thin-Film Transistor by UV-Irradiation Treatment...200**
U. Hanifah^{1,*)}, J.P.S. Bermundo¹⁾, M. Uenuma¹⁾ and Y. Uraoka¹⁾
¹⁾ *Nara Institute of Science and Technology, JAPAN*

Closing Remarks (16:10~16:15)